



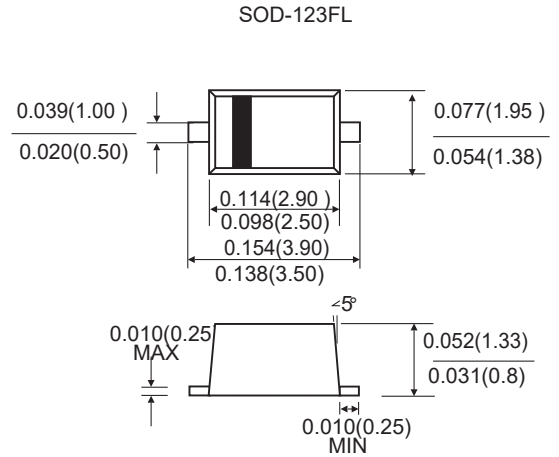
# Silicon Rectifiers

## A1 THRU A7 50 to 1000 V 1.0A

- Plastic package has Underwriters Laboratory
- Flammability Classification 94V-O Utilizing Flame
- Retardant Epoxy Molding Compound.
- For surface mounted applications.
- Exceeds environmental standards of MIL-S-19500/228
- Low leakage current.

### Mechanical Data

- Case : Molded plastic, JEDEC SOD-123FL
- Terminals : Solder plated, solderable per MIL-STD-750,
- Method 2026
- Polarity : Indicated by c athode band
- Mounting Position : Any



Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60HZ, resistive or inductive load. For capacitive load, derate current by 20%.

Type Numbe And Device Marking	Symbol	A1	A2	A3	A4	A5	A6	A7	Unit
		S1A FM4001	S1B FM4002	S1D FM4003	S1G FM4004	S1J FM4005	S1K FM4006	S1M FM4007	
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Working Peak Reverse Voltage	V <sub>RWM</sub>								
DC Blocking Voltage	V <sub>R</sub>								
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	800	
Maximum Average Rectified Output Current @60Hz sine wave, Resistance load, T <sub>a</sub> (Fig 1)	I <sub>(AV)</sub>	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30							A
Maximum Forward Voltage at I <sub>(AV)</sub> and T <sub>A</sub> =25°C	V <sub>FM</sub>	1.0							V
Peak Reverse Current @T <sub>A</sub> = 25°C	I <sub>RM</sub>	10							μA
At Rated DC Blocking Voltage @T <sub>A</sub> = 100°C		500							
Typical Junction Capacitance (Note 1)	C <sub>j</sub>	16							pF
Typical Thermal Resistance (Note 2) Between junction and ambient, On alumina substrate	R <sub>θJa</sub>	70							°C/W
Typical Thermal Resistance (Note 2) Between junction and lead	R <sub>θJL</sub>	30							°C/W
Typical Thermal Resistance (Note 2) Between junction and lcase	R <sub>θJc</sub>	40							°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +150							°C

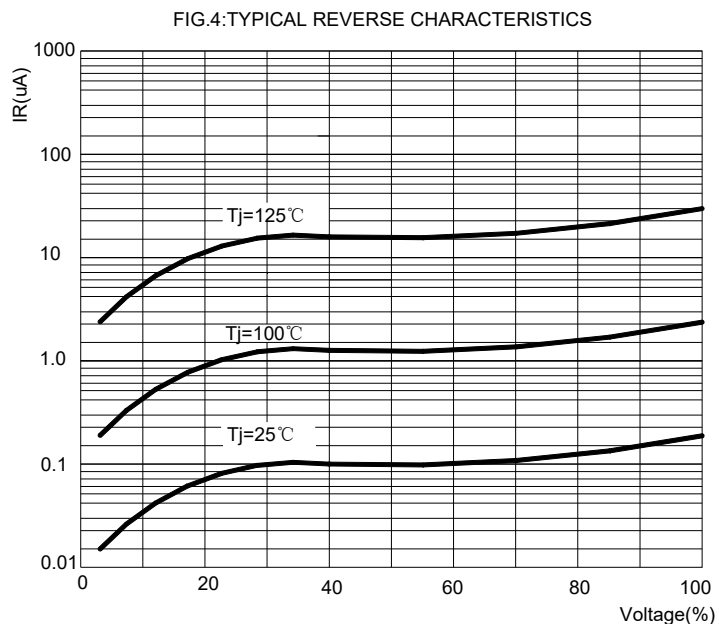
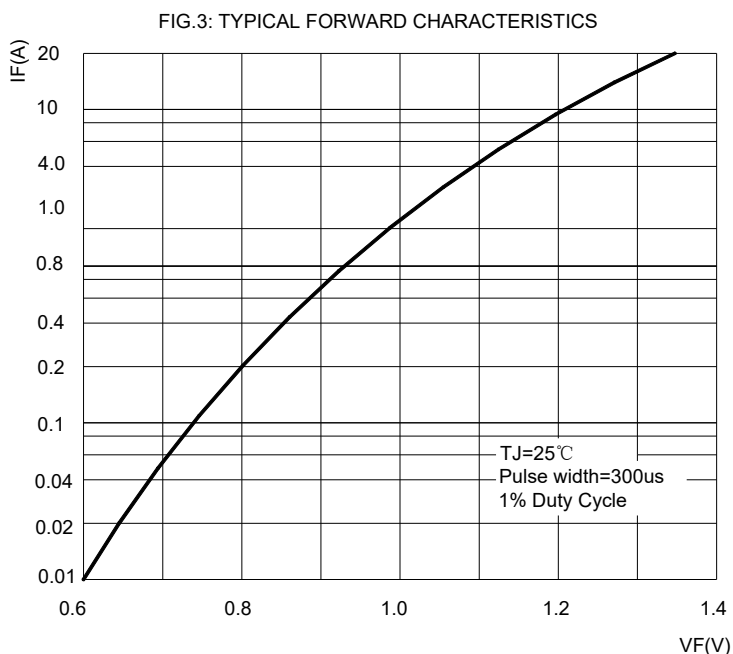
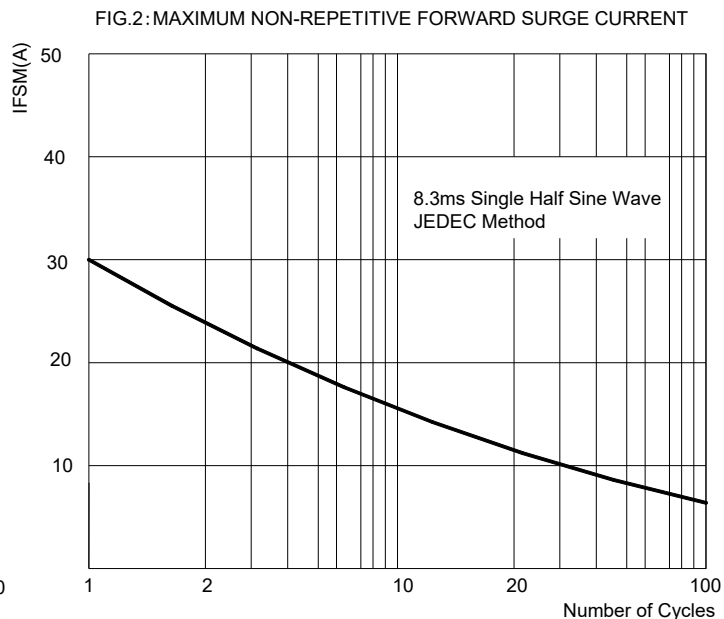
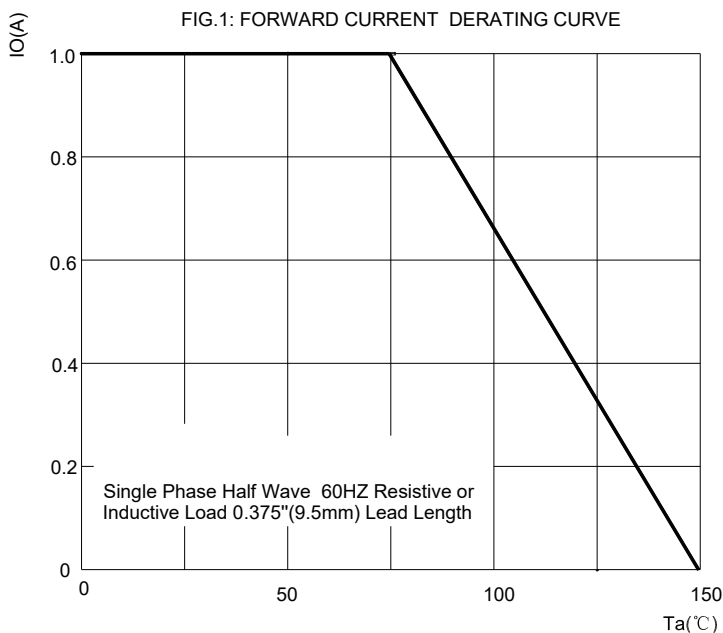
Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.
- 2.P.C.B. mounted with 0.2 X 0.2"(5.0 X 5.0mm)copper pad areas



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